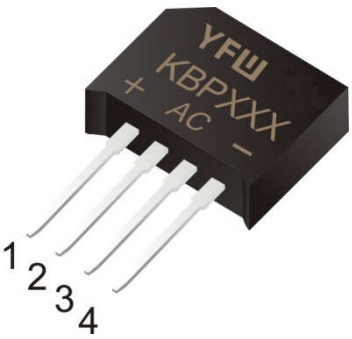
6.0A GLASS PASSIVATED BRIDGE RECTIFIER

Reverse Voltage - 100 to 1000 V

Forward Current – 6.0A



1.Output Anode(+)
2.Input pin(~)
3.Input pin(~)
4.Output Cathode(-)

KBP

FEATURES

- High current capability
- Low forward voltage drop
- Glass Passivated Chip Junction
- Low power loss, high efficiency
- Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- Case: KBP
- Terminals: Solderable per MIL-STD-202, Method 208
- Approx. Weight: 1.52g / 0.05oz

Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter		Symbols	KBP601	KBP602	KBP604	KBP606	KBP608	KBP610	Units
Maximum Repetitive Peak Reverse Voltage		V_{RRM}	100	200	400	600	800	1000	V
Maximum RMS voltage		V_{RMS}	70	140	280	420	560	700	V
Maximum DC Blocking Voltage		V_{DC}	100	200	400	600	800	1000	V
Average Rectified Output Current		$I_{(AV)}$	6						A
Peak Forward Surge Current 8.3 ms Single Half Sine-Wave Superimposed on Rated Load (JEDEC method)		I_{FSM}	165						A
Forward Voltage per element @IF =3.0A DC		V_F	1.0						V
Maximum DC Reverse Current @Tj=25°C at Rated DC Blocking Voltage @Tj=25°C		I_R	10 500						μA
I2t Rating for Fusing(3ms≤t≤8.3ms)		I^2t	93						A^2S
Maximum Typical Thermal Resistanc	wwithout heatsink wwith heatsink wwithout heatsink	$R_{\theta JA/}$ $R_{\theta JC}$	55 1.5 15						°C/W
Operating and Storage Temperature Range		T_j, T_{stg}	-55 ~ +150						°C

（1）Measured at 1 MHz and applied reverse voltage of 4 V D.C

（2）Device mounted on 50mm*50mm*1.6mm Cu plate heatsink

Ratings And Characteristic Curves

FIG.1-DERATING CURVE OUTPUT RECTIFIED CURRENT

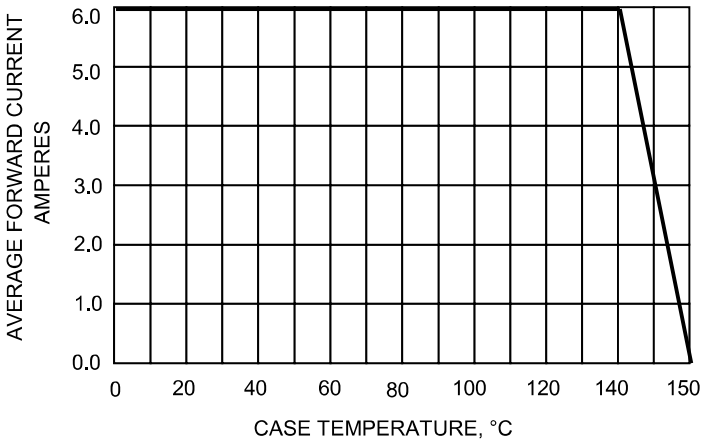


FIG.2-MAXIMUM NON-REPETITIVE SURGE CURRENT

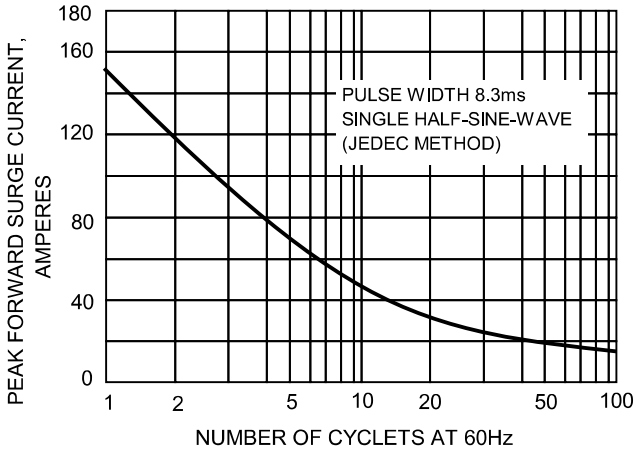


FIG.3-TYPICAL FORWARD CHARACTERISTICS

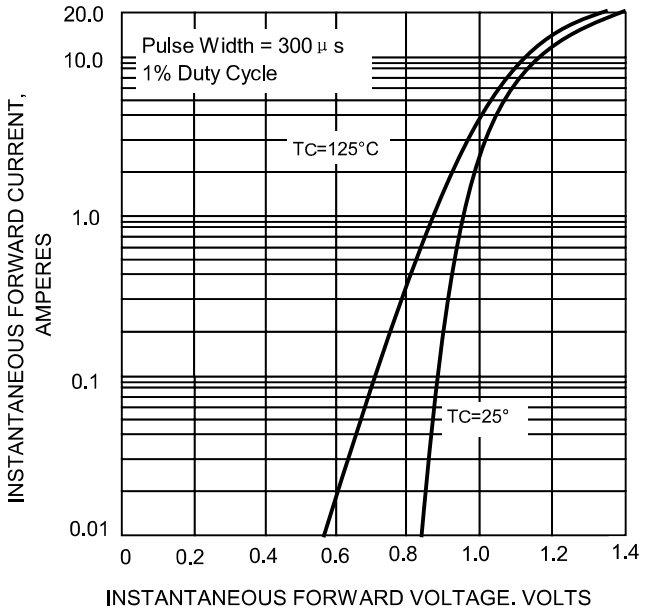
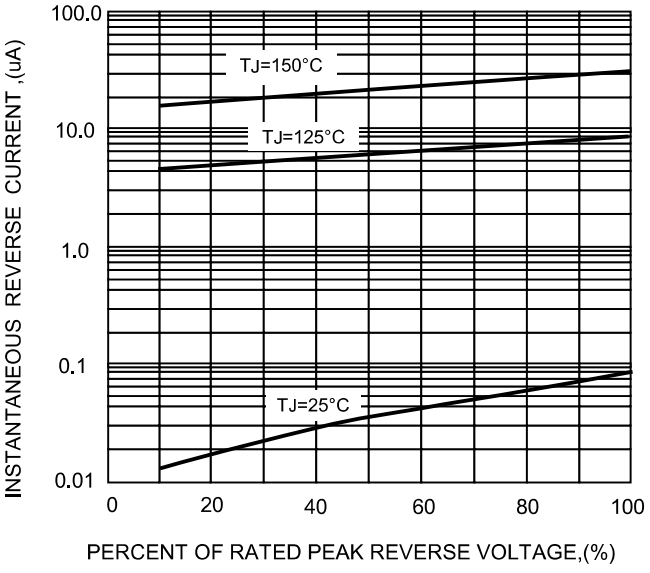
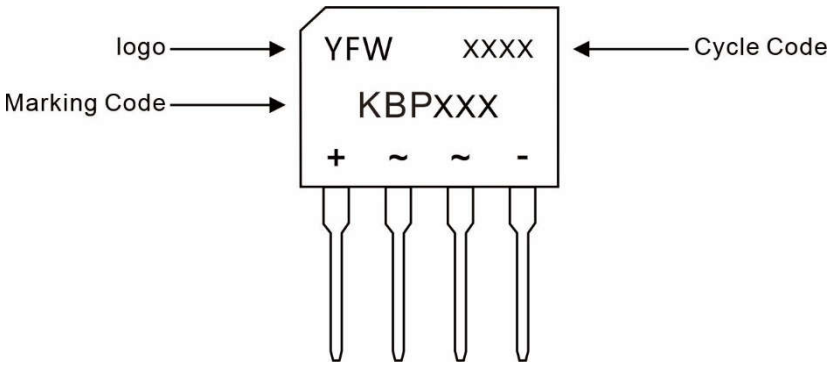


FIG.5-TYPICAL REVERSE CHARACTERISTICS



Marking Diagram

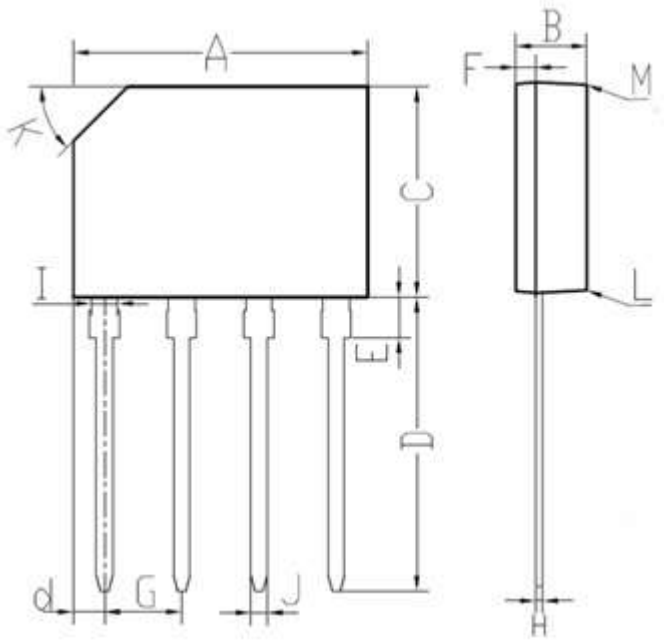


Ordering information

Package	Packing Description	Packing Quantity
KBP	bulk	500PCS/Box 5000PCS/Carton

Package Dimensions

KBP



Dim.	Millimeter(mm)		Dimensions inInch	
	Min.	Max.	Min.	Max.
A	14.3	14.60	0.56	0.57
B	3.0	3.3	0.12	0.13
c	10.45	10.75	0.41	0.42
D	14.41	14.71	0.57	0.58
d	1.40	1.70	0.06	0.07
E	2.0	2.30	0.09	0.09
F	0.90	1.20	0.04	0.05
G	3.50	3.80	0.14	0.15
H	0.35	0.37	0.01	0.01
I	1.43	1.45	0.06	0.06
J	0.8	0.83	0.03	0.03
K	2.7×45°（Typ）		0.11×45°（Typ）	
L	#	3°	#	3°
M	#	2°	#	2°

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